

Precision Wide-Bandwidth Analog Switch

Features

- Rail-To-Rail operation
- Pin-compatible with 3125 Bus Switch & 74 series 125
- Single-Supply operation: 2V to 6V
- Low On-Resistance: 8Ω typical @ 5V
- Tight match between channels: 0.9Ω typical
- R_{ON} flatness: 3Ω typical
- Low power consumption: 0.5μ-ohm typical
- High Speed, T_{ON} = 8ns typical
- High-current channel capability: >100mA
- Wide bandwidth: >200 MHz
- Packaging (Pb-free & Green available):
 - 14-pin SOIC (W)
 - 16-pin QSOP (Q)

Applications

- Instrumentation, ATE
- Audio Switching and Routing
- Telecommunications Systems
- Data Communications
- Battery-Powered Systems
- Replaces Mechanical Relays

Description

Pericom Semiconductor's PI5A101 is an all-purpose analog switch designed for single-supply operation from +2V to +6V. This switch is ideal for audio, video, and data switching and routing.

The PI5A101 is a quad SPST (single-pole, single-throw) NC (normally closed) function.

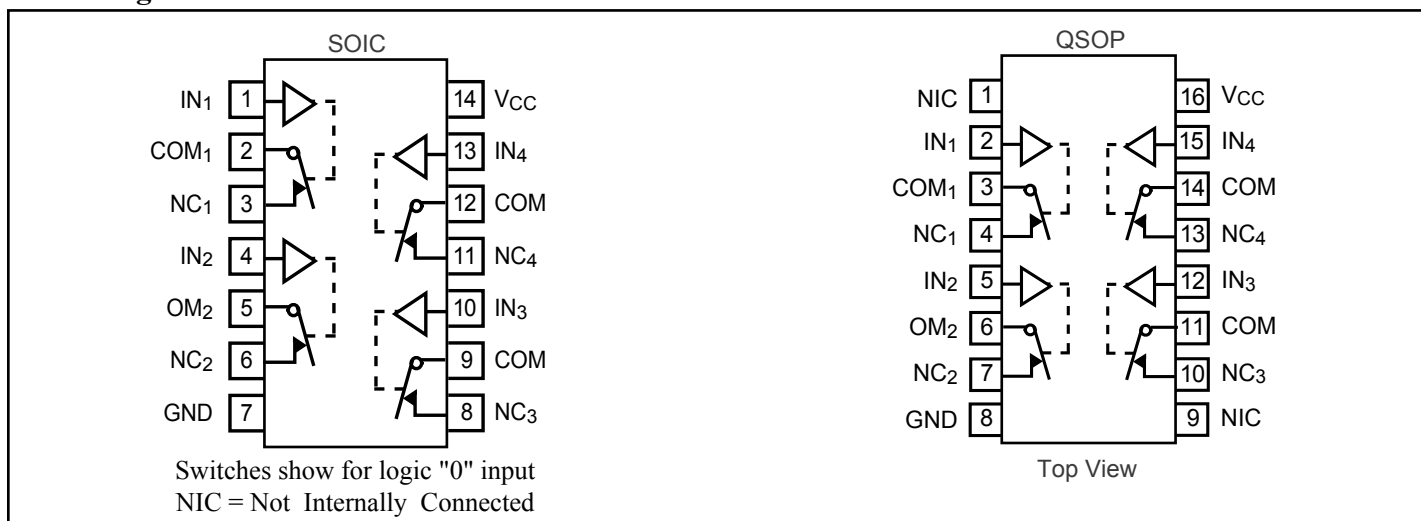
When on, each switch conducts current equally well in either direction. When off, they block voltages up to the power-supply rails.

The PI5A101 is fully specified with +5V and +3.3V supplies. With +5V the R_{ON} is 8Ω typical, making it ideal for replacing mechanical relays in data communications, test equipment, and instrumentation applications. Matching between channels is better than 2Ω. R_{ON} flatness is better than 4Ω over the specified range.

These analog switches also offer wide bandwidth (>200 MHz high speed (T_{ON} >15ns), and low charge injection (Q >10pC).

The PI5A101 is available in the narrow-body 14-pin small SOIC and 16-pin QSOP packages for operation over the industrial (-40°C to +85°C) temperature range.

Pin Configurations



Truth Table

| Logic | Switch |
|-------|--------|
| 0 | ON |
| 1 | OFF |

Electrical Specifications - Single +5V Supply ($V_{CC} = +5V \pm 10\%$, $GND = 0V$, $V_{INH} = 2.4V$, $V_{INL} = 0.8V$)

| Parameter | Symbol | Conditions | Temp.(°C) | Min. ⁽¹⁾ | Typ. ⁽²⁾ | Max. ⁽¹⁾ | Units | |
|---|--------------------------------|---|-----------|---------------------|---------------------|---------------------|----------|---------|
| Analog Switch | | | | | | | | |
| Analog Signal Range ⁽³⁾ | V_{ANALOG} | | Full | 0 | | V_{CC} | V | |
| On-Resistance | R_{ON} | $V_{CC} = 4.5V$, $I_{COM} = -30mA$, V_{NO} or $V_{NC} = +2.5V$ | 25 | | 8 | 10 | Ω | |
| On-Resistance Match Between Channels ⁽⁴⁾ | ΔR_{ON} | | Full | | | 18 | | |
| On-Resistance Flatness ⁽⁵⁾ | $R_{FLAT(ON)}$ | $V_{CC} = 5V$, $I_{COM} = -30mA$, V_{NO} or $V_{NC} = 1V, 2.5V, 4V$ | 25 | | 0.9 | 2 | | |
| | | | Full | | | 4 | | |
| NO or NC Off Leakage Current ⁽⁶⁾ | $I_{NO(OFF)}$ or $I_{NC(OFF)}$ | $V_{CC} = 5.5V$, $V_{COM} = 0V$, V_{NO} or $V_{NC} = 4.5V$ | 25 | | 0.05 | | nA | |
| COM Off Leakage Current ⁽⁶⁾ | $I_{COM(OFF)}$ | | Full | -80 | | 80 | | |
| COM On Leakage Current ⁽⁶⁾ | $I_{COM(ON)}$ | $V_{CC} = 5.5V$, $V_{COM} = +4.5V$, V_{NO} or $V_{NC} = +4.5V$ | 25 | | 0.05 | | | |
| | | | Full | -80 | | 80 | | |
| Logic Input | | | | | | | | |
| Input High Voltage | V_{IH} | Guaranteed logic High Level | Full | | | | V | |
| Input Low Voltage | V_{IL} | Guaranteed logic Low Level | | | | | | |
| Input Current with Voltage High | I_{INH} | $V_{IN} = 2.4V$, all others = 0.8V | | | | | 0.8 | μA |
| Input Current with Voltage Low | I_{INL} | $V_{IN} = 0.8V$, all others = 2.4V | | | | | -1 | |

Electrical Specifications - Single +5V Supply ($V_{CC} = +5V \pm 10\%$, $GND = 0V$, $V_{INH} = 2.4V$, $V_{INL} = 0.8V$) (continued)

| Parameter | Symbol | Conditions | Temp.(°C) | Min. ⁽¹⁾ | Typ. ⁽²⁾ | Max. ⁽¹⁾ | Units |
|---------------------------------|----------------|---|-----------|---------------------|---------------------|---------------------|-------|
| Dynamic | | | | | | | |
| Turn-On Time | t_{ON} | $V_{CC} = 5V$, see figure 1 | 25 | | 8 | 15 | ns |
| | | | Full | | | 20 | |
| Turn-Off Time | t_{OFF} | | 25 | | 3.5 | 7 | |
| | | | Full | | | 10 | |
| Charge Injection ⁽³⁾ | Q | $C_L = 1nF$, $V_{GEN} = 0V$, $R_{GEN} = 0V$, Figure 2 | 25 | | 7 | 10 | pC |
| Off Isolation | O_{IRR} | $R_L = 50\Omega$, $C_L = 5pF$, $f = 10MHz$, see figure 3 | | | -55 | | dB |
| Crosstalk ⁽⁸⁾ | $I_{COM(OFF)}$ | $R_L = 50\Omega$, $C_L = 5pF$, $f = 10MHz$, see figure 4 | | | -92 | | |
| NC or NO Capacitance | $C_{(OFF)}$ | $f = 1kHz$, see figure 5 | | | 8 | | pF |
| COM Off Capacitance | $C_{COM(OFF)}$ | | | | 8 | | |
| COM On Capacitance | $C_{COM(ON)}$ | $f = 1kHz$, see figure 6 | | | 14 | | |
| 3-dB Bandwidth | BW | $R_L = 10k\Omega$ | Full | | 230 | | MHz |
| Distortion ⁽⁹⁾ | D | | | | 0.03 | | % |
| Supply | | | | | | | |
| Power-Supple Range | V_{CC} | | Full | 2 | | 6 | V |
| Positve Supply Current | I_{CC} | $V_{CC} = 3.6V$, $V_{IN} = 0V$ or $V+$, All Channels on or off | | | | | 1 |

Absolute Maximum Ratings

| | |
|---|---------------------------------|
| Voltages Referenced to GND | |
| V _{CC} | -0.5V to +7V |
| V _{IN} , V _{COM} , V _{NC} ⁽¹⁾ | -0.5V to V _{CC} +2V |
| | or 30mA, whichever occurs first |
| Current (any terminal except COM, NO, NC)..... | 30mA |
| Current: COM, NO, NC (pulsed at 1ms, 10% duty cycle) | 120mA |

Thermal Information

| | |
|--|-----------------|
| Continuous Power Dissipation | |
| Narrow SO & QSOP (derate 8.7mW/°C above +70°C) | 650mW |
| Storage Temperature | -65°C to +150°C |
| Lead Temperature (soldering, 10s) | +300°C |

Notes

1. Signals on NC, COM, or IN exceeding V_{CC} or GND are clamped by internal diodes. Limit forward diode current to 30mA.
2. Caution: Stresses beyond those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied.

Electrical Specifications-Single +3.3V Supply (V_{CC} = +3.3V ± 10%, GND = 0V, V_{INH} = 2.4V, V_{INL} = 0.8V)

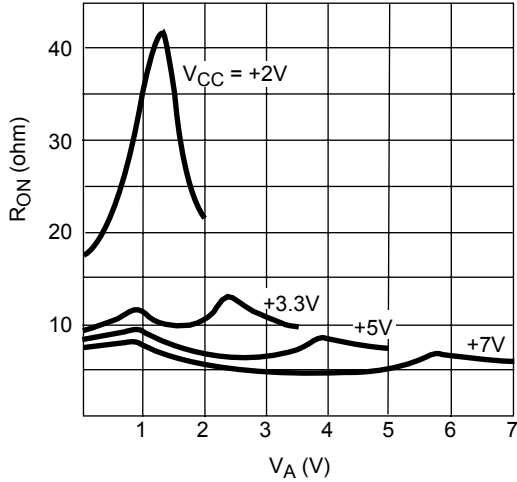
| Parameter | Symbol | Conditions | Temp.(°C) | Min. ⁽¹⁾ | Typ. ⁽²⁾ | Max. ⁽¹⁾ | Units |
|---|-----------------------|---|-----------|---------------------|---------------------|---------------------|-------|
| Analog Switch | | | | | | | |
| Analog Signal Range ⁽³⁾ | V _{ANALOG} | | Full | 0 | | V _{CC} | V |
| On-Resistance | R _{ON} | V _{CC} = 3V, I _{COM} = -30mA, V _{NO} or V _{NC} = 1.5V | 25 | | 7.2 | 18 | Ω |
| | | | Full | | | 28 | |
| On-Resistance Match Between Channels ⁽⁴⁾ | ΔR _{ON} | V _{CC} = 3.3V, I _{COM} = -30mA, V _{NO} or V _{NC} = 0.8V, 2.5V | 25 | | 0.2 | 2 | |
| | | | Full | | | 4 | |
| On-Resistance Flatness ^(3,5) | R _{FLAT(ON)} | V _{CC} = 3.3V, I _{COM} = -30mA, V _{NO} or V _{NC} = 0.8V, 2.5V | 25 | | 2.72 | 10 | |
| | | | Full | | | 12 | |
| Dynamic | | | | | | | |
| Turn-On Time | t _{ON} | V _{CC} = 3.3V, V _{NO} or V _{NC} = 1.5V, see figure 1 | 25 | | 7 | 25 | ns |
| | | | Full | | | 40 | |
| Turn-Off Time | t _{OFF} | V _{CC} = 3.3V, V _{NO} or V _{NC} = 1.5V, see figure 1 | 25 | | 1 | 12 | |
| | | | Full | | | 20 | |
| Charge Injection ⁽³⁾ | Q | C _L = 1nF, V _{GEN} = 0V, R _{GEN} = 0Ω, Figure 2 | 25 | | 1.6 | 10 | pC |
| Supply | | | | | | | |
| Positive Supply Current | I _{CC} | V _{CC} = 3.6V, V _{IN} = 0V or V _{CC} , All Channels on or off | Full | | | 1 | μA |

Notes:

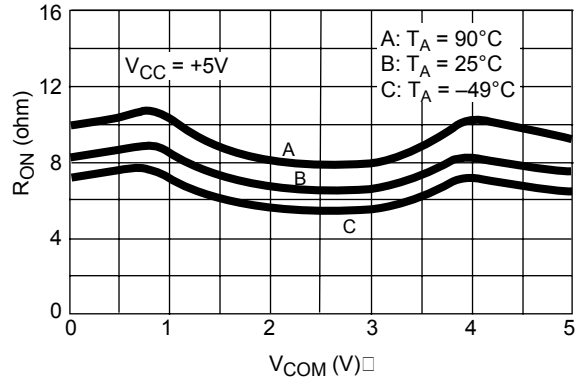
1. The algebraic convention, where most negative value is a minimum and most positive is a maximum, is used in this data sheet.
2. Typical values are for DESIGN AID ONLY, not guaranteed or subject to production testing.
3. Guaranteed by design
4. ΔR_{ON} = R_{ON} MAX - R_{ON} MIN
5. Flatness is defined as the difference between the maximum and minimum value of On-Resistance measured.
6. Leakage parameters are 100% tested at maximum rated hot temperature and guaranteed by correlation at +25°C.
7. Off Isolation = 20log₁₀ V_B / V_A. See Figure 3.
8. Between any two switches. See Figure 4.
9. D = R_{FLAT(ON)}/R_L.

Typical Operating Characteristics ($T_A = +25^\circ\text{C}$, unless otherwise noted)

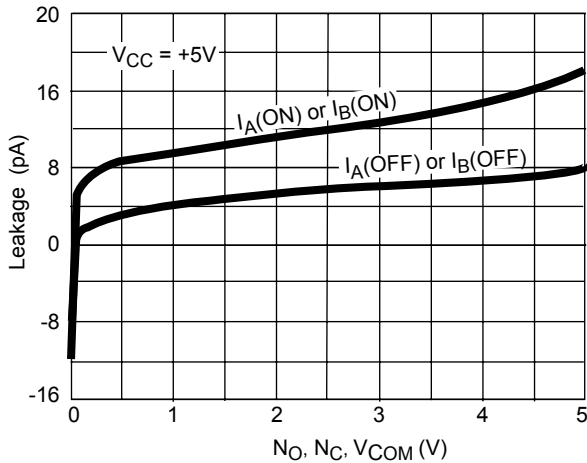
R_{ON} vs. V_{COM}



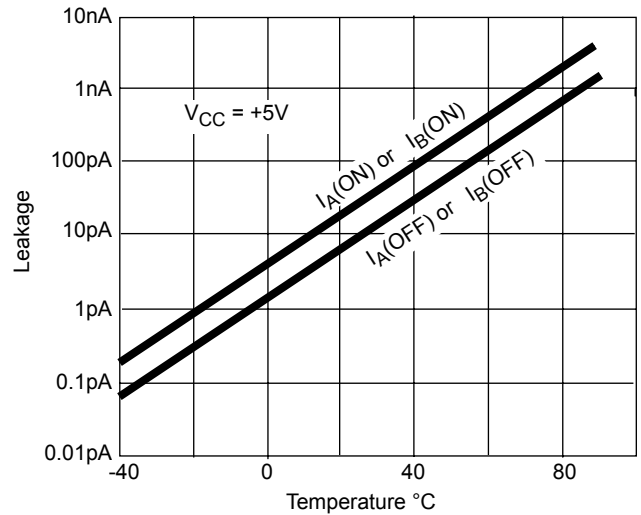
R_{ON} vs. V_{COM} and Temperature



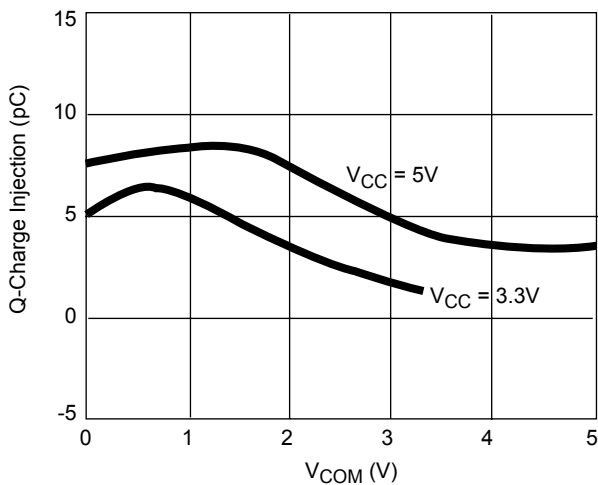
Leakage Currents vs. Analog Voltage



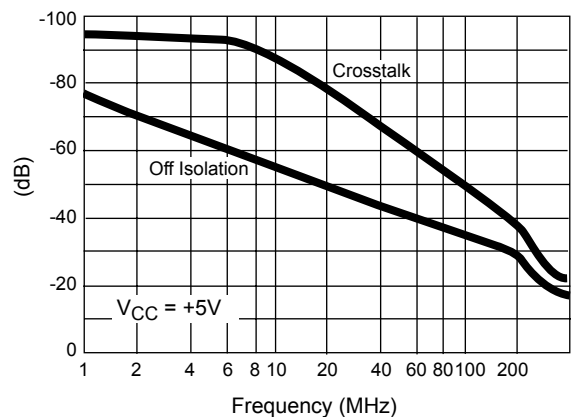
Leakage Current vs. Temperature



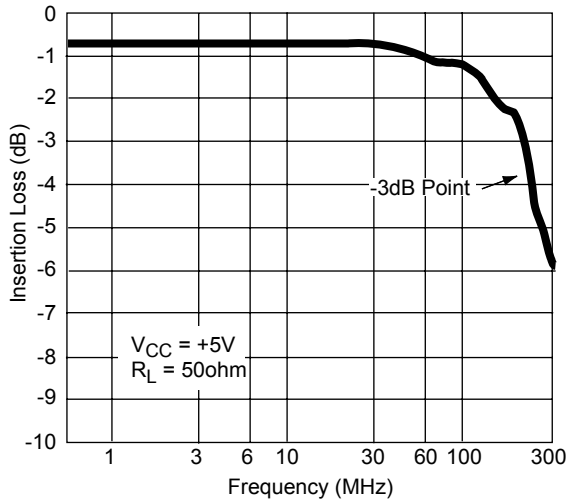
Charge Injection vs. Analog Voltage



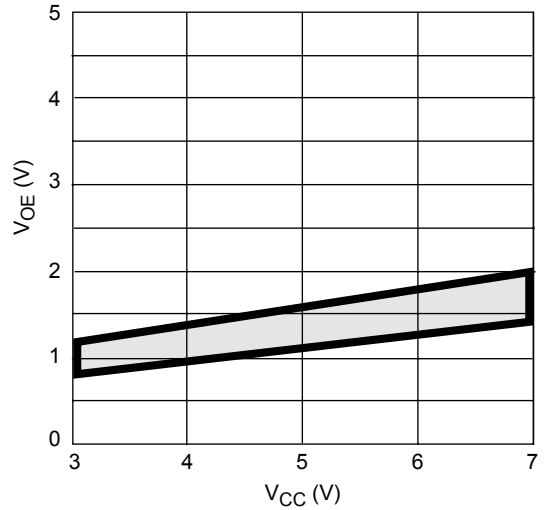
Crosstalk and Off-Isolation vs. Frequency



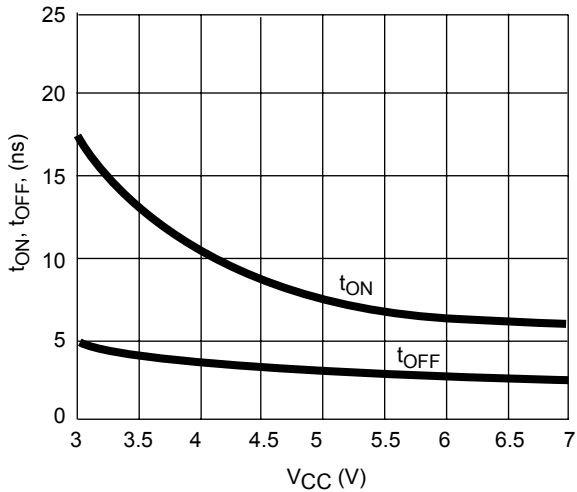
Insertion Loss vs. Frequency



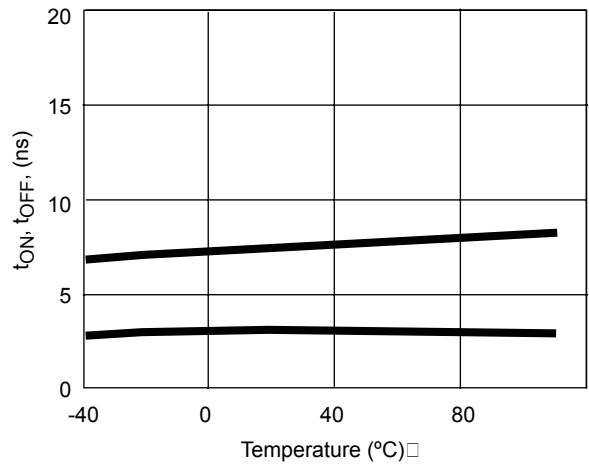
Input Switching Threshold vs. Supply Voltage



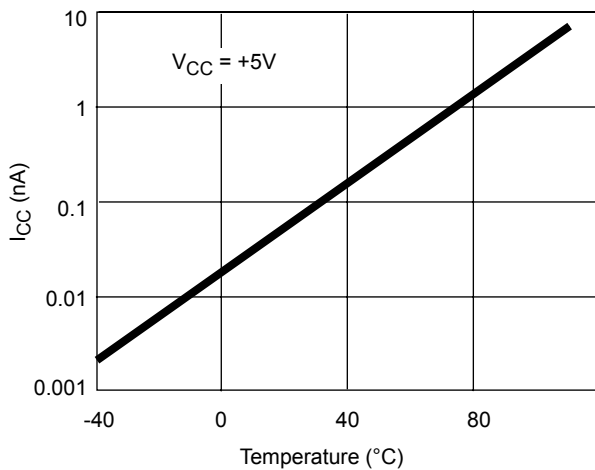
Switching Times vs. V_{CC}



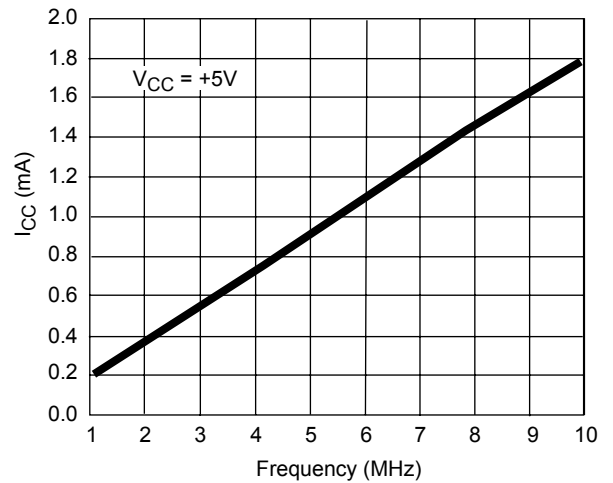
Switching Times vs. Temperature



Supply Current vs. Temperature



Supply Current vs. Input Switching Frequency



Test Circuits/Timing Diagrams

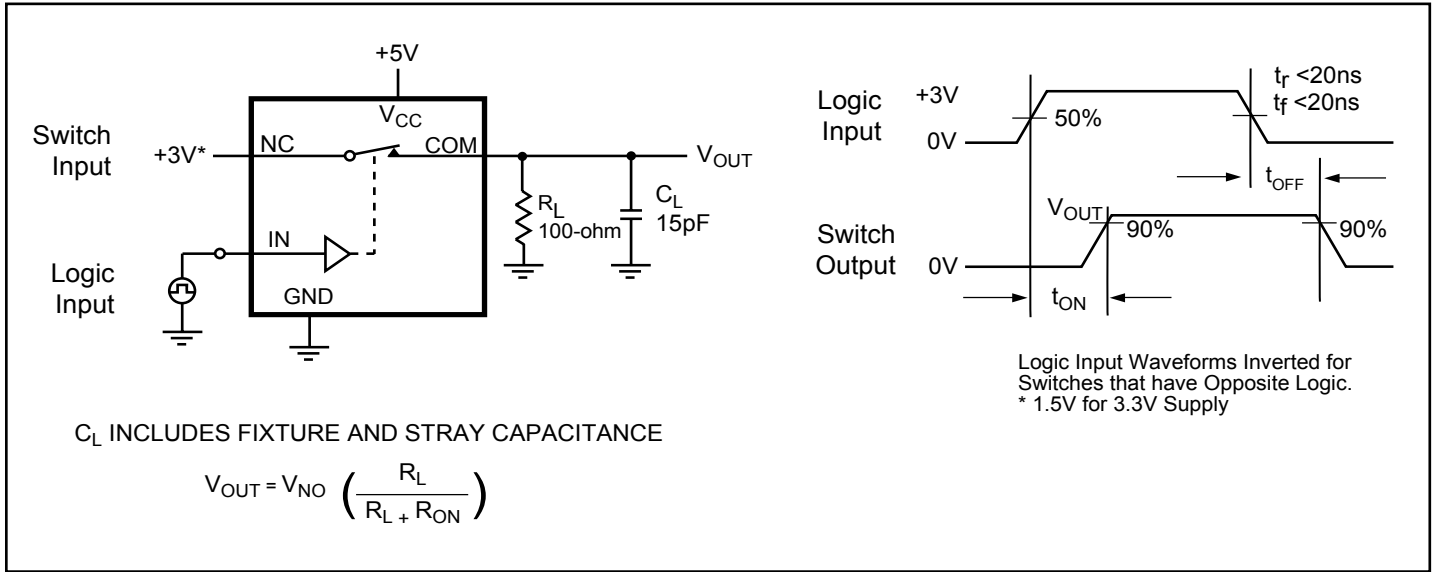


Figure 1. Switching Time

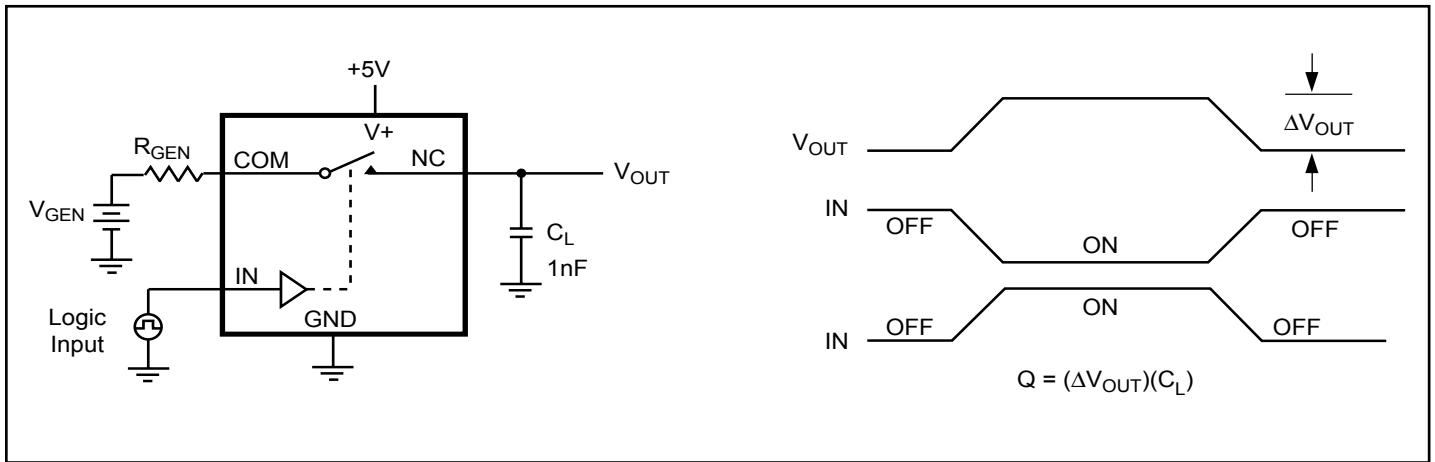


Figure 2. Charge Injection

Test Circuits/Timing Diagrams (continued)

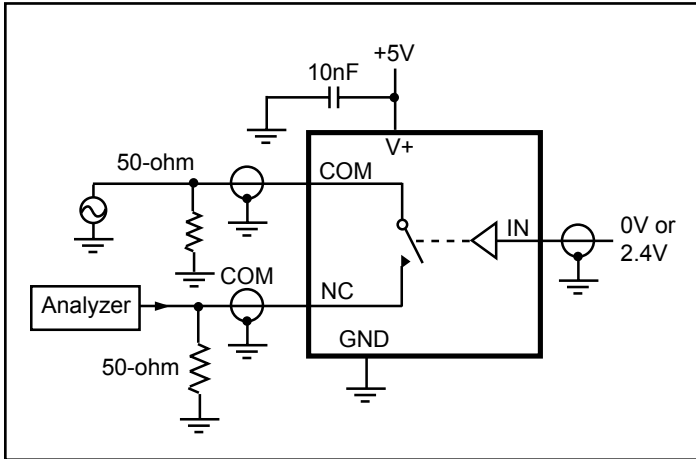


Figure 3. Off Isolation

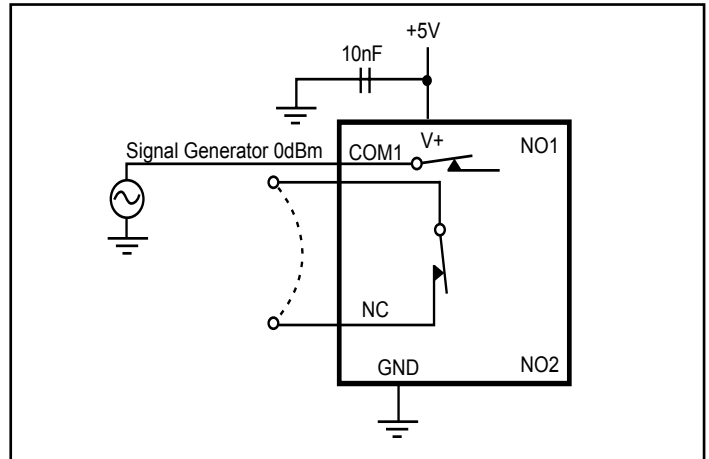


Figure 4. Crosstalk

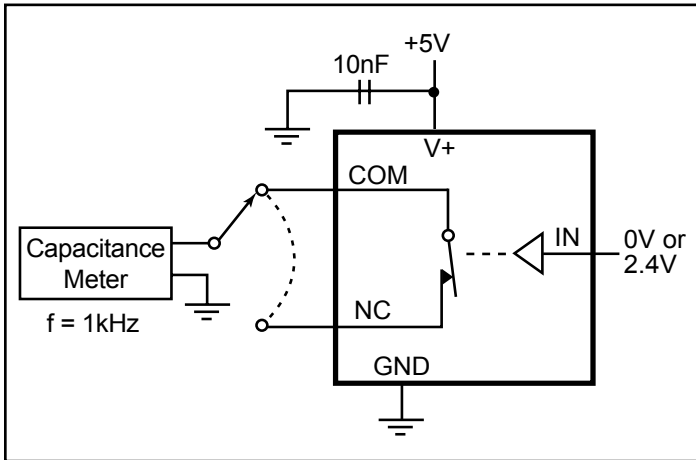


Figure 5. Channel-Off Capacitance

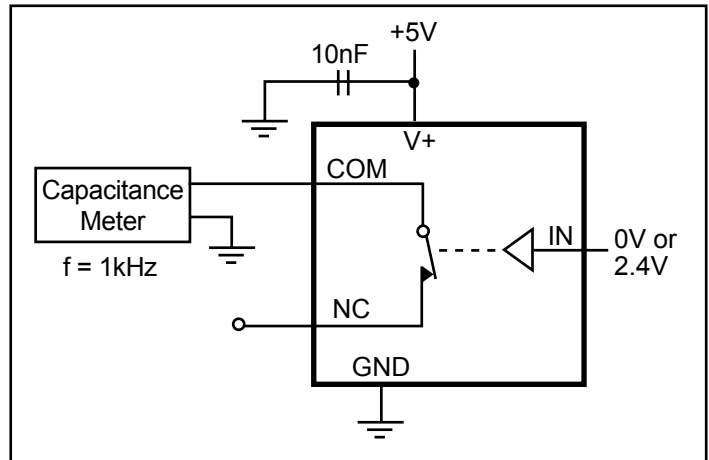


Figure 6. Channel-On Capacitance

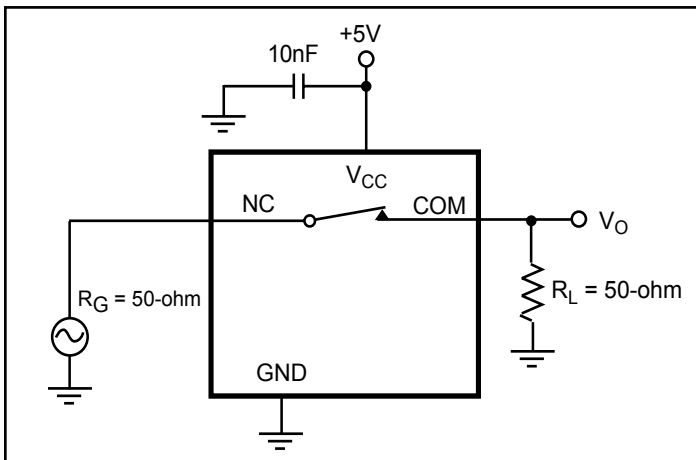
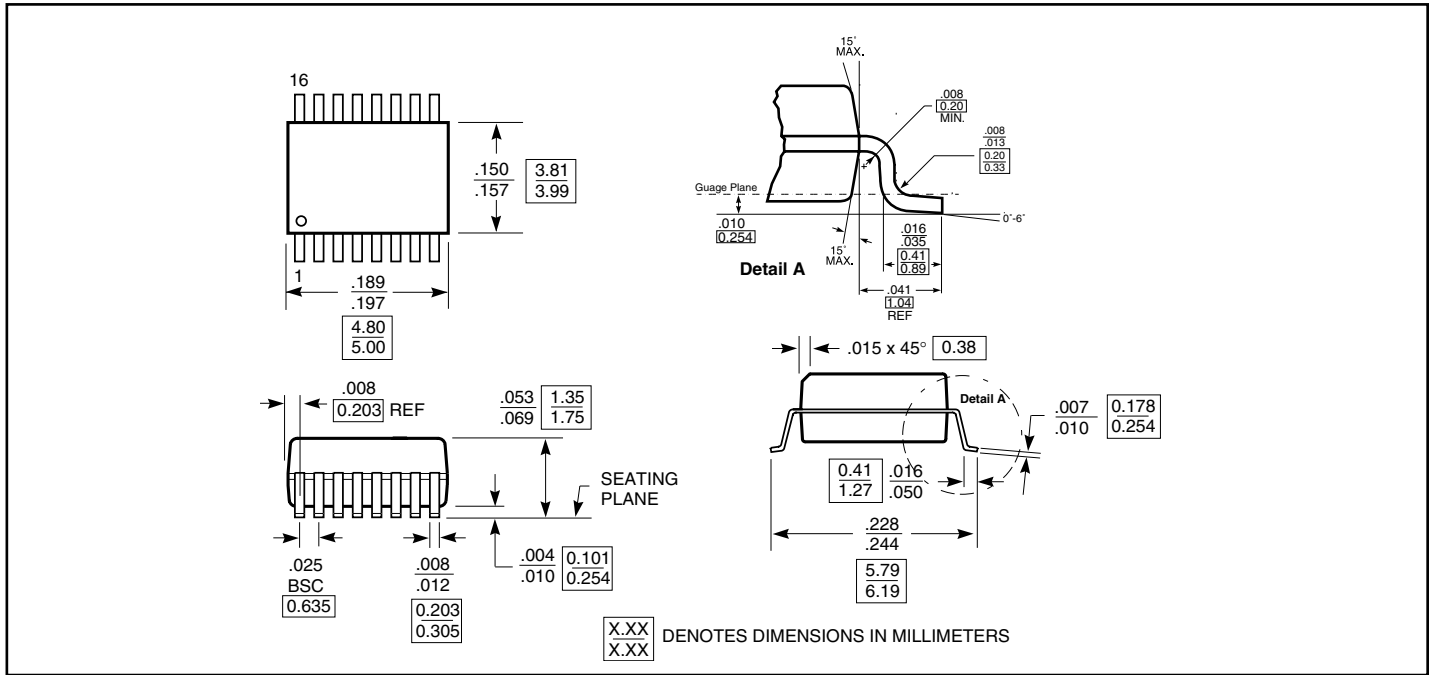
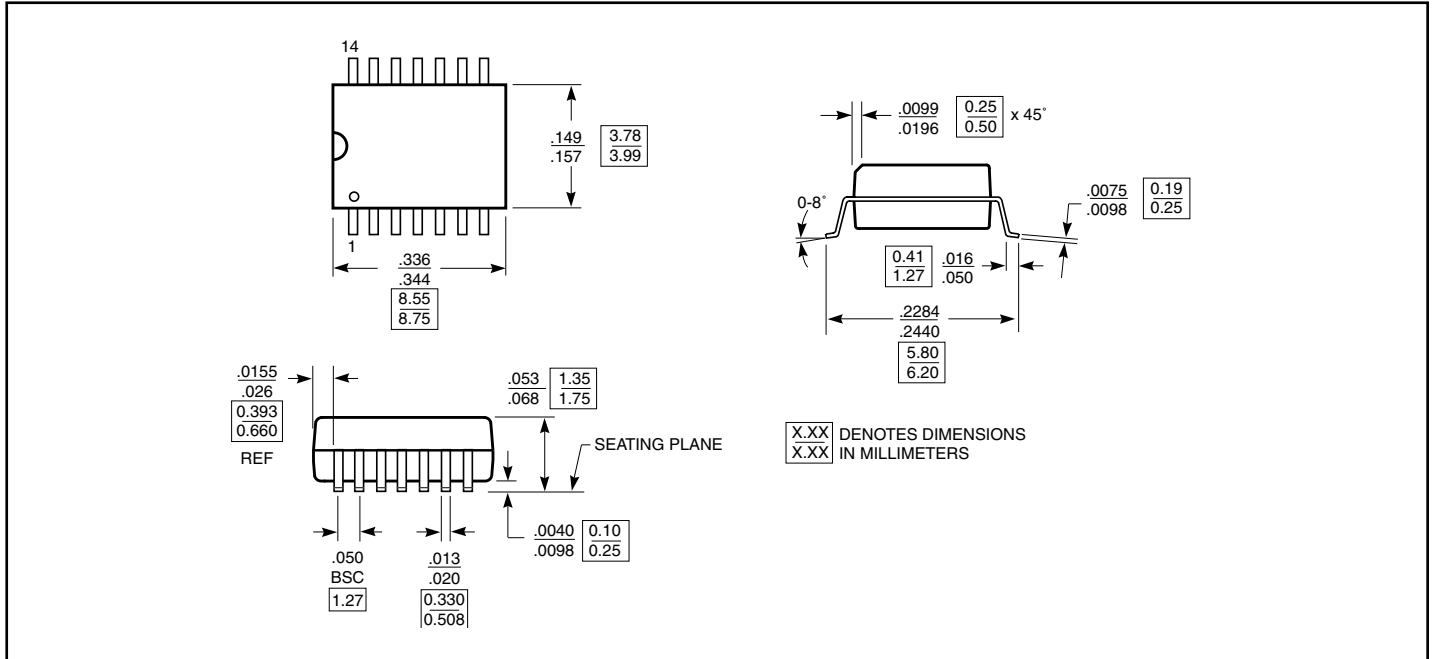


Figure 7. Bandwidth

Packaging Mechanical: 16-Pin, QSOP (Q)



Packaging Mechanical: 14-Pin, SOIC (W)



Ordering Information

| Ordering Code | Package Code | Package Description |
|----------------------|---------------------|-------------------------------|
| PI5A101Q | Q | 16-pin, QSOP |
| PI5A101QE | Q | Pb-free & Green, 16-pin, QSOP |
| PI5A101W | W | 14-pin SOIC |
| PI5A101WE | W | Pb-free & Green, 14-pin SOIC |

Notes:

1. Thermal characteristics can be found on the company web site at www.pericom.com/packaging/